

RELIABILITY REPORT

FOR

MAX11047ETN+

PLASTIC ENCAPSULATED DEVICES

August 8, 2011

MAXIM INTEGRATED PRODUCTS

120 SAN GABRIEL DR. SUNNYVALE, CA 94086

Approved by
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Quality Assurance
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Conclusion

The MAX11047ETN+ successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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I. Device Description

A. General

The MAX11047/MAX11048/MAX11049 and MAX11057/MAX11058/MAX11059 16-bit/14-bit ADCs offer 4, 6, or 8 independent input channels. Featuring independent track and hold (T/H) and SAR circuitry, these parts provide simultaneous sampling at 250ksps for each channel. The devices accept a 0 to +5V input. All inputs are overrange protected with internal ±20mA input clamps providing overrange protection with a simple external resistor. Other features include a 4MHz T/H input bandwidth, internal clock, and internal or external reference. A 20MHz, bidirectional, parallel interface provides the conversion results and accepts digital configuration inputs. The devices operate with a 4.75V to 5.25V analog supply and a separate flexible 2.7V to 5.25V digital supply for interfacing with the host without a level shifter. The MAX11047/MAX11048/MAX11049 are available in a 56-pin TQFN and 64-pin TQFP packages while the MAX11057/MAX11058/MAX11059 are available in TQFP only. All devices operate over the extended -40°C to +85°C temperature range.



II. Manufacturing Information

A. Description/Function: 4-/6-/8-Channel, 16-/14-Bit, Simultaneous-Sampling ADCs

B. Process: S45
C. Number of Device Transistors: 166153
D. Fabrication Location: Texas
E. Assembly Location: Thailand

F. Date of Initial Production: December 23, 2009

III. Packaging Information

A. Package Type: 56-pin TQFN 8x8

B. Lead Frame: Copper

C. Lead Finish:

D. Die Attach:

Conductive

E. Bondwire:

Au (1 mil dia.)

F. Mold Material:

Epoxy with silica

F. Mold Material: Epoxy with silica filler
 G. Assembly Diagram: #05-9000-2916 / D
 H. Flammability Rating: Class UL94-V0

I. Classification of Moisture Sensitivity per Level 3

JEDEC standard J-STD-020-C

J. Single Layer Theta Ja: 35°C/W
K. Single Layer Theta Jc: 1°C/W
L. Multi Layer Theta Ja: 21°C/W
M. Multi Layer Theta Jc: 1°C/W

IV. Die Information

A. Dimensions: 171 X 228 mils

B. Passivation: Si₃N₄/SiO₂ (Silicon nitride/ Silicon dioxide)

C. Interconnect: Al/0.5%Cu with Ti/TiN Barrier

D. Backside Metallization: None

E. Minimum Metal Width: Metal1 = 0.5 / Metal2 = 0.6 / Metal3 = 0.6 microns (as drawn)
 F. Minimum Metal Spacing: Metal1 = 0.45 / Metal2 = 0.5 / Metal3 = 0.6 microns (as drawn)

G. Bondpad Dimensions:

H. Isolation Dielectric: SiO₂I. Die Separation Method: Wafer Saw



V. Quality Assurance Information

A. Quality Assurance Contacts: Richard Aburano (Manager, Reliability Engineering)

Don Lipps (Manager, Reliability Engineering)

Bryan Preeshl (Vice President of QA)

B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.

0.1% For all Visual Defects.

C. Observed Outgoing Defect Rate: < 50 ppm
D. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (λ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \times 4340 \times 96 \times 2}$$
 (Chi square value for MTTF upper limit)

 $\lambda = 11.5 \times 10^{-9}$
 $\lambda = 11.5 \text{ F.I.T.}$ (60% confidence level @ 25°C)

The following failure rate represents data collected from Maxim's reliability monitor program. Maxim performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at http://www.maxim-ic.com/qa/reliability/monitor. Cumulative monitor data for the S45 Process results in a FIT Rate of 0.49 @ 25C and 8.49 @ 55C (0.8 eV, 60% UCL)

B. E.S.D. and Latch-Up Testing (lot THZYFU002O D/C 1043)

The AC80-1 die type has been found to have all pins able to withstand a HBM transient pulse of +/-2500V per JEDEC JESD22-A114. Latch-Up testing has shown that this device withstands a current of +/-100mA and overvoltage per JEDEC JESD78.



Table 1 Reliability Evaluation Test Results

MAX11047ETN+

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	COMMENTS		
Static Life Test (Note 1)							
	Ta = 135°C	DC Parameters	48	0	SHZZDQ001A, D/C 0931		
	Biased	& functionality	48	0	SHZZBQ002B, D/C 0817		
	Time = 192 hrs.						

Note 1: Life Test Data may represent plastic DIP qualification lots.